

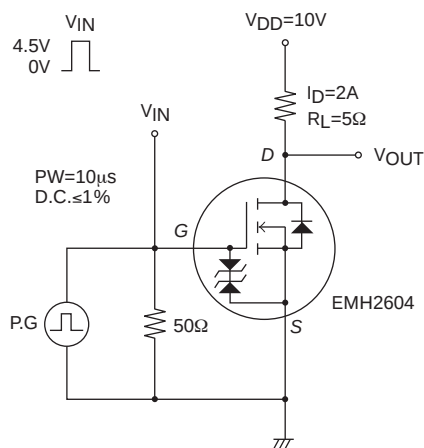
<http://onsemi.com>

EMH2604

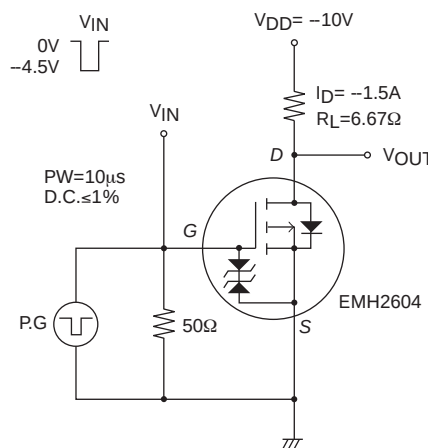
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[N-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=2A		3.4		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=4A, VGS=4.5V		34	45	mΩ
	RDS(on)2	ID=1A, VGS=2.5V		49	67	mΩ
	RDS(on)3	ID=0.5A, VGS=1.8V		74	115	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		345		pF
Output Capacitance	Coss			67		pF
Reverse Transfer Capacitance	Crss			52		pF
Turn-ON Delay Time	tD(on)	See specified Test Circuit.		9.2		ns
Rise Time	tr			60		ns
Turn-OFF Delay Time	tD(off)			30		ns
Fall Time	tf			38		ns
Total Gate Charge	Qg	VDS=10V, VGS=4.5V, ID=4A		4.7		nC
Gate-to-Source Charge	Qgs			0.65		nC
Gate-to-Drain “Miller” Charge	Qgd			1.6		nC
Diode Forward Voltage	VSD	IS=4A, VGS=0V		0.8	1.2	V
[P-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-20V, VGS=0V			-1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-0.4		-1.3	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-1.5A		3.6		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-3A, VGS=-4.5V		65	85	mΩ
	RDS(on)2	ID=-1A, VGS=-2.5V		98	137	mΩ
	RDS(on)3	ID=-0.5A, VGS=-1.8V		155	235	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		320		pF
Output Capacitance	Coss			66		pF
Reverse Transfer Capacitance	Crss			50		pF
Turn-ON Delay Time	tD(on)	See specified Test Circuit.		7.1		ns
Rise Time	tr			21		ns
Turn-OFF Delay Time	tD(off)			37		ns
Fall Time	tf			32		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-4.5V, ID=-3A		4.0		nC
Gate-to-Source Charge	Qgs			0.6		nC
Gate-to-Drain “Miller” Charge	Qgd			1.1		nC
Diode Forward Voltage	VSD	IS=-3A, VGS=0V		-0.83	-1.2	V

Switching Time Test Circuit
[N-channel]

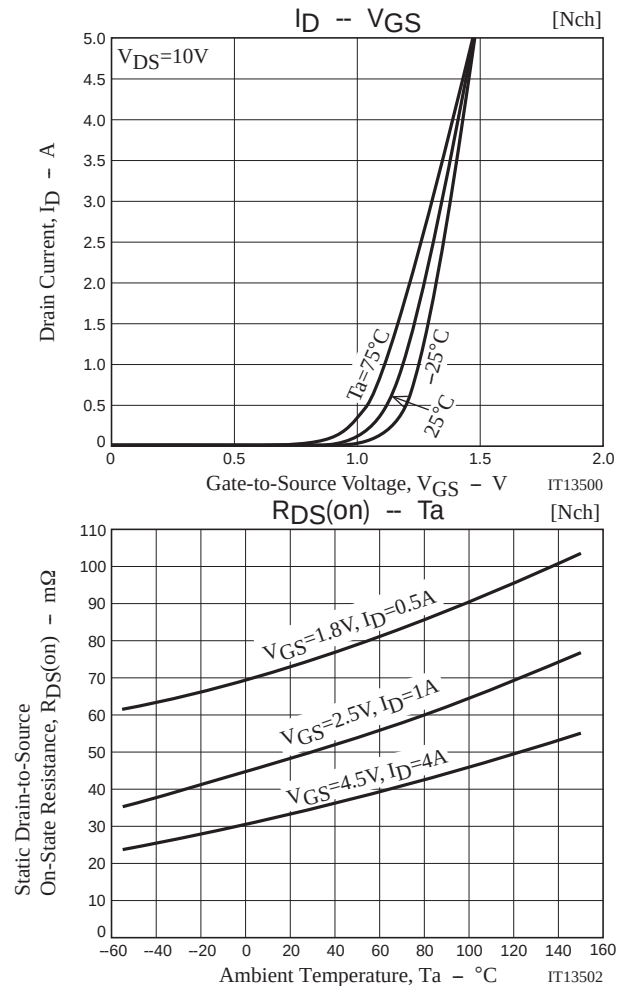
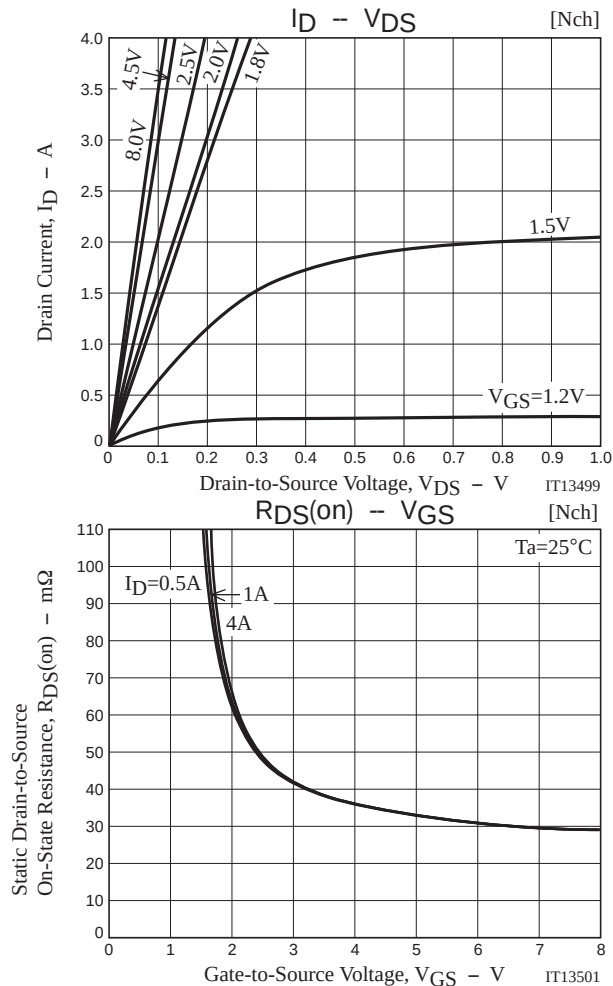


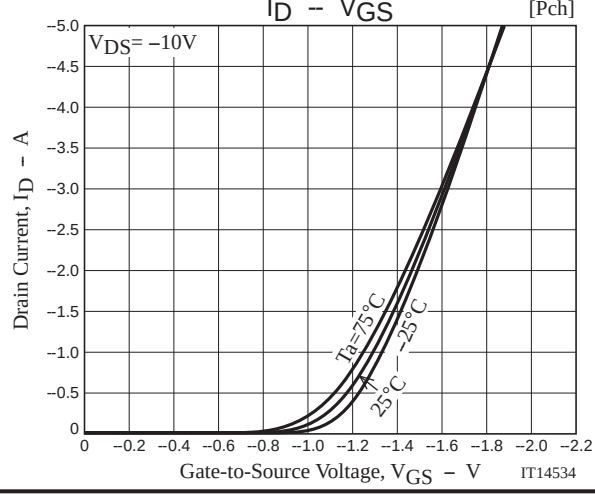
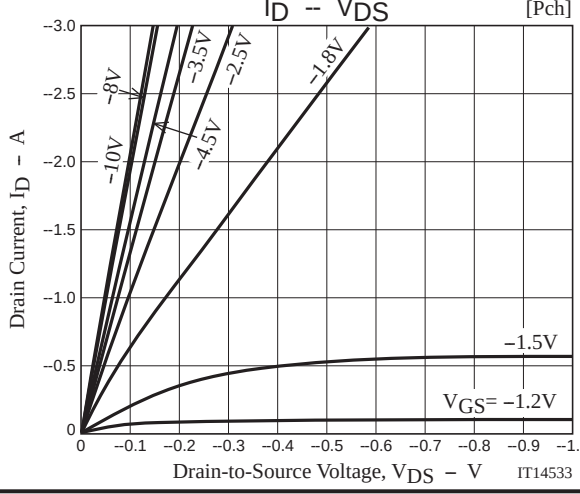
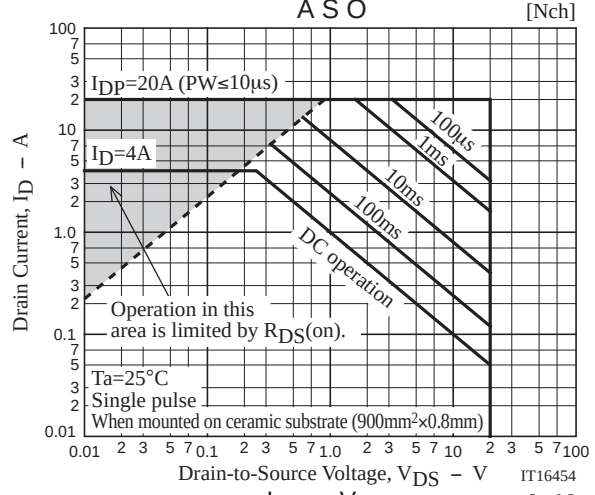
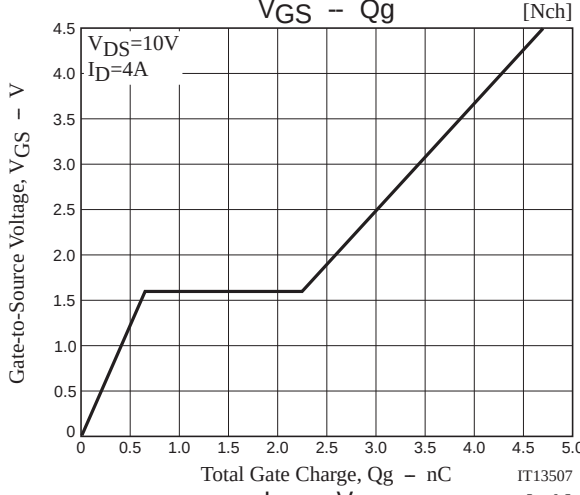
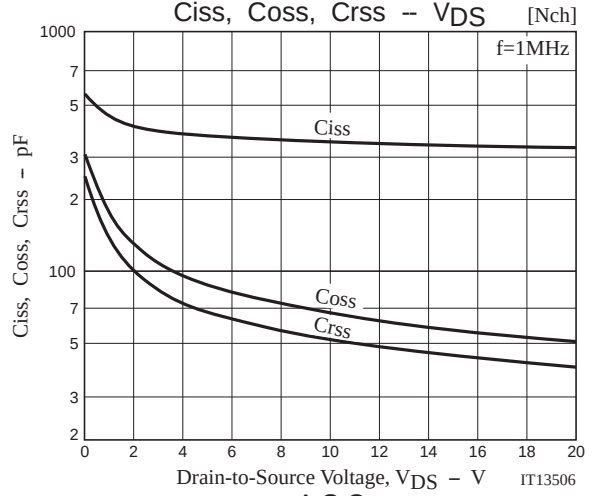
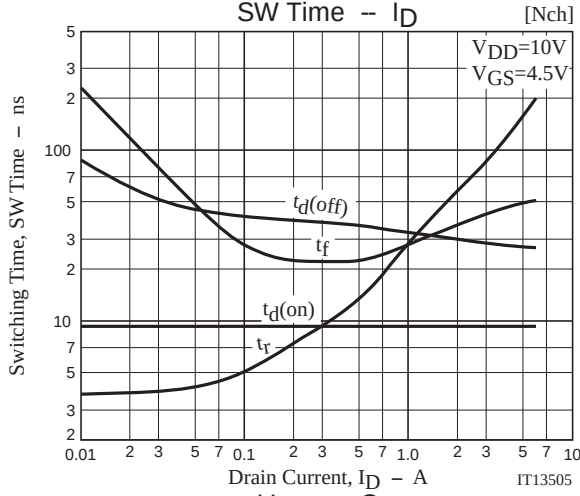
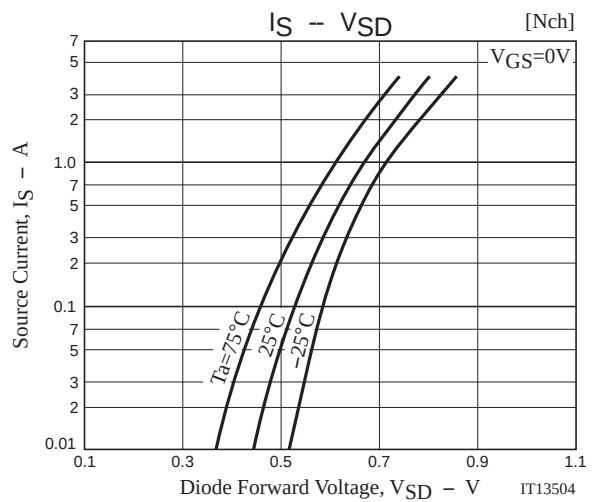
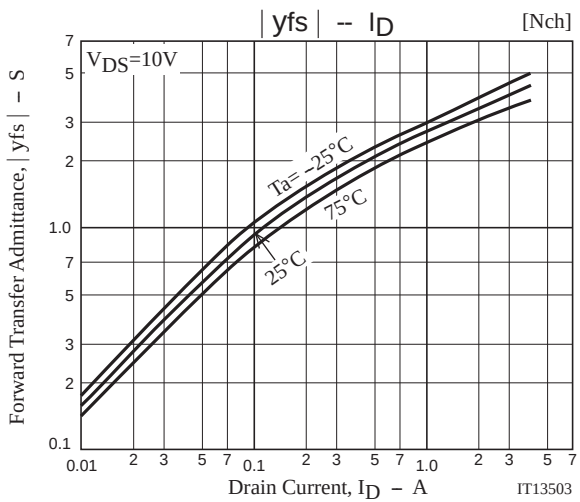
[P-channel]

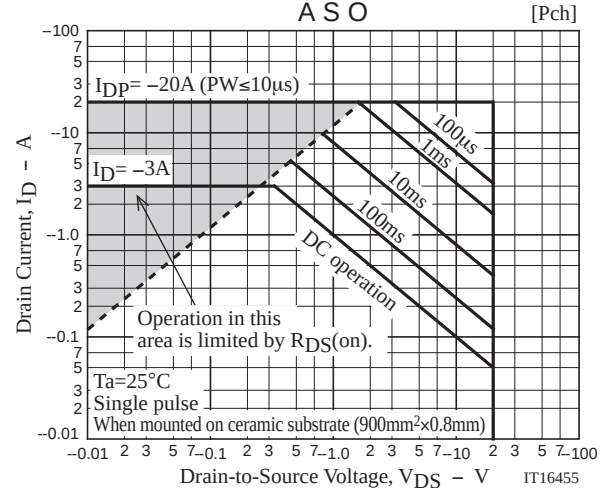
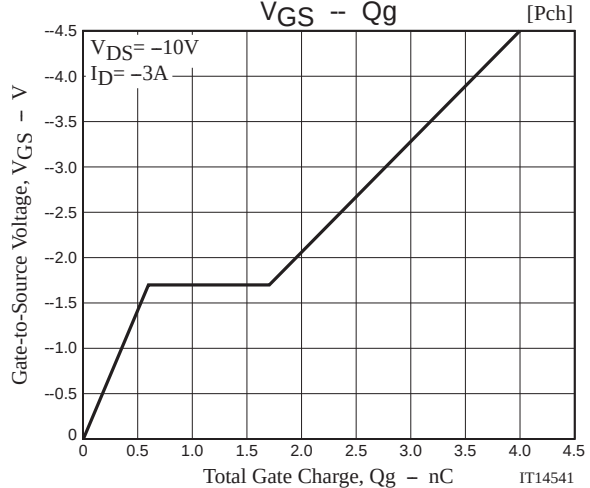
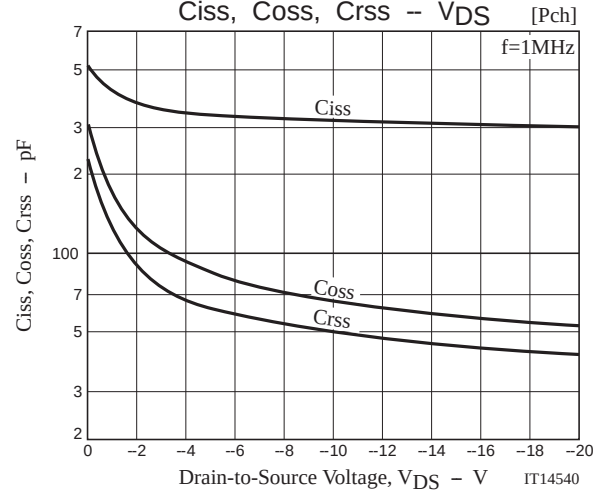
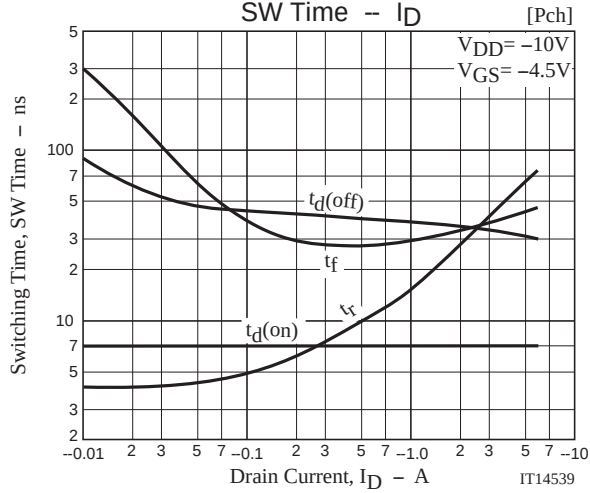
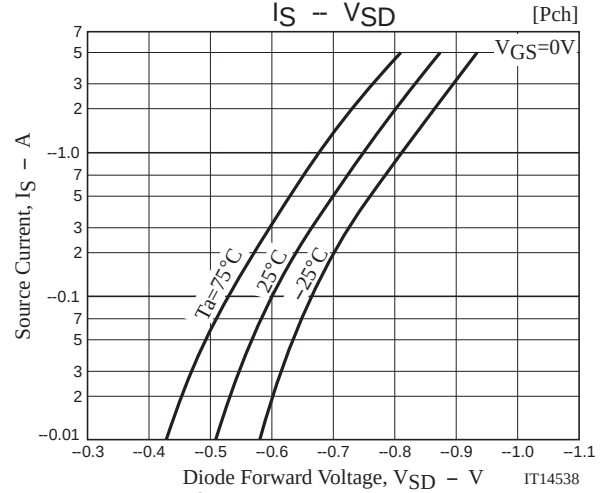
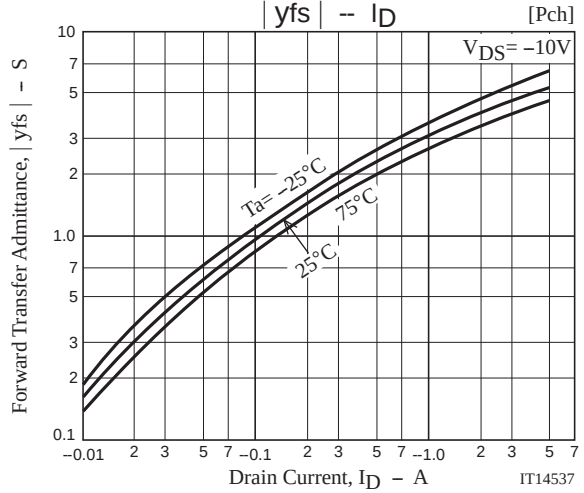
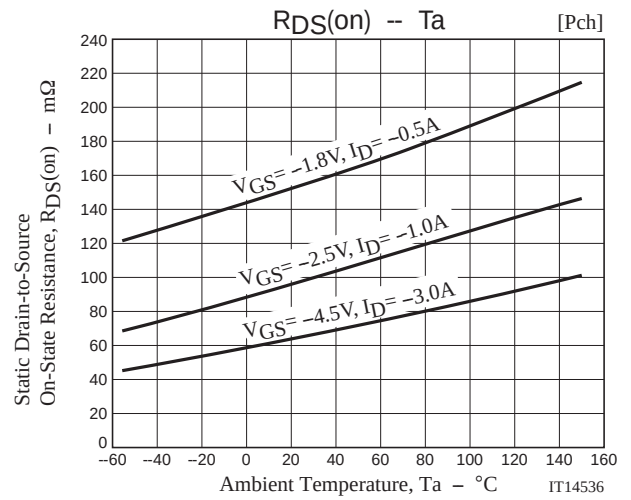
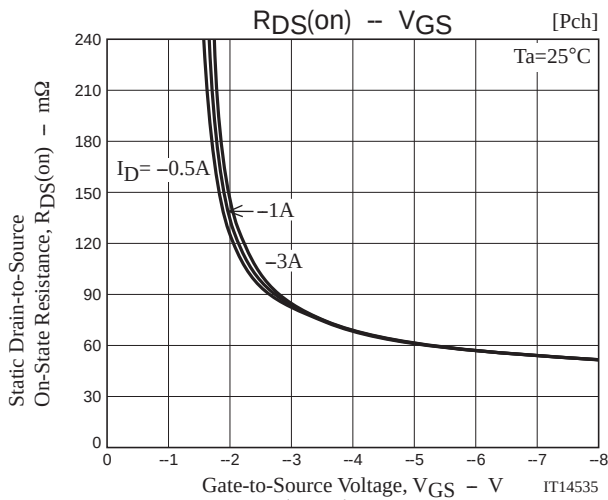


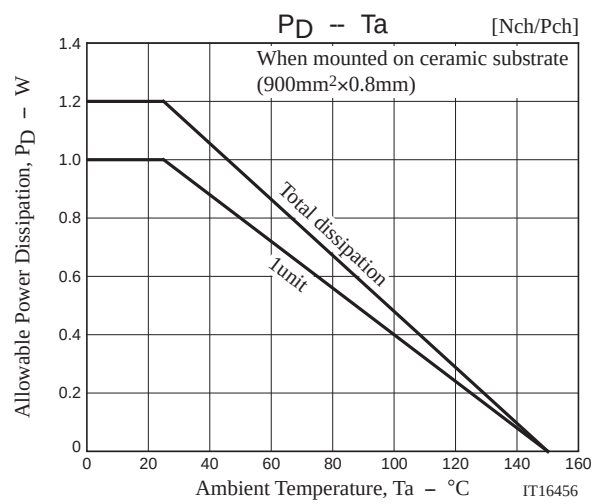
Ordering Information

Device	Package	Shipping	memo
EMH2604-TL-H	EMH8	3,000pcs./reel	Pb Free and Halogen Free









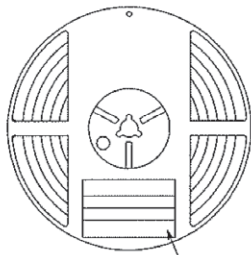
Embossed Taping Specification

EMH2604-TL-H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
EMH8	MCP4	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

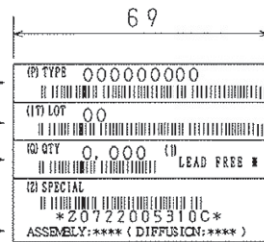
Packing method



Type No.
LOT No.
Quantity
Origin

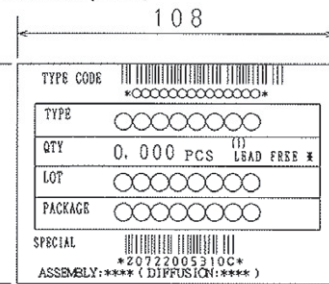
Reel label

Reel label, Inner box label
(unit:mm)



Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.



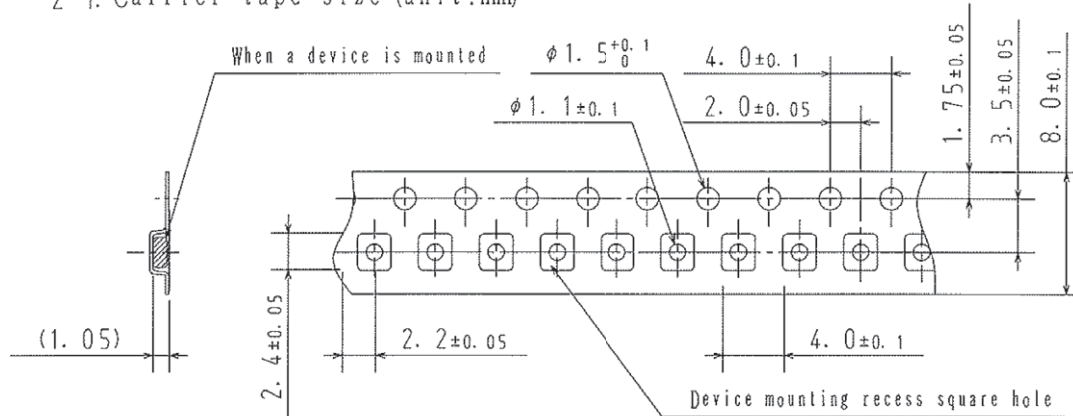
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

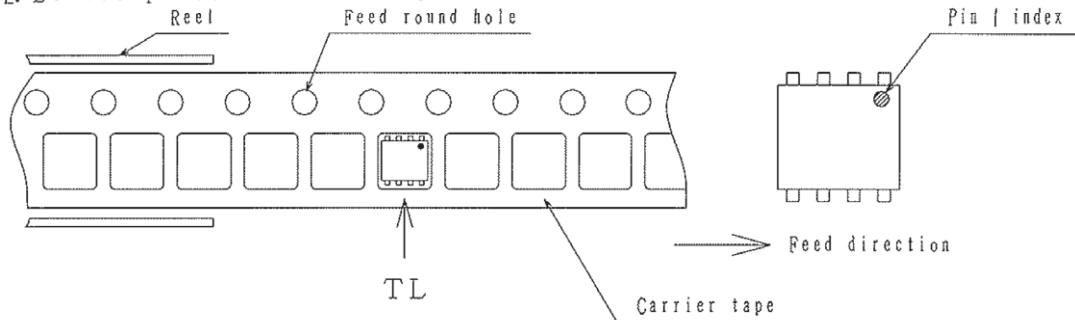
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

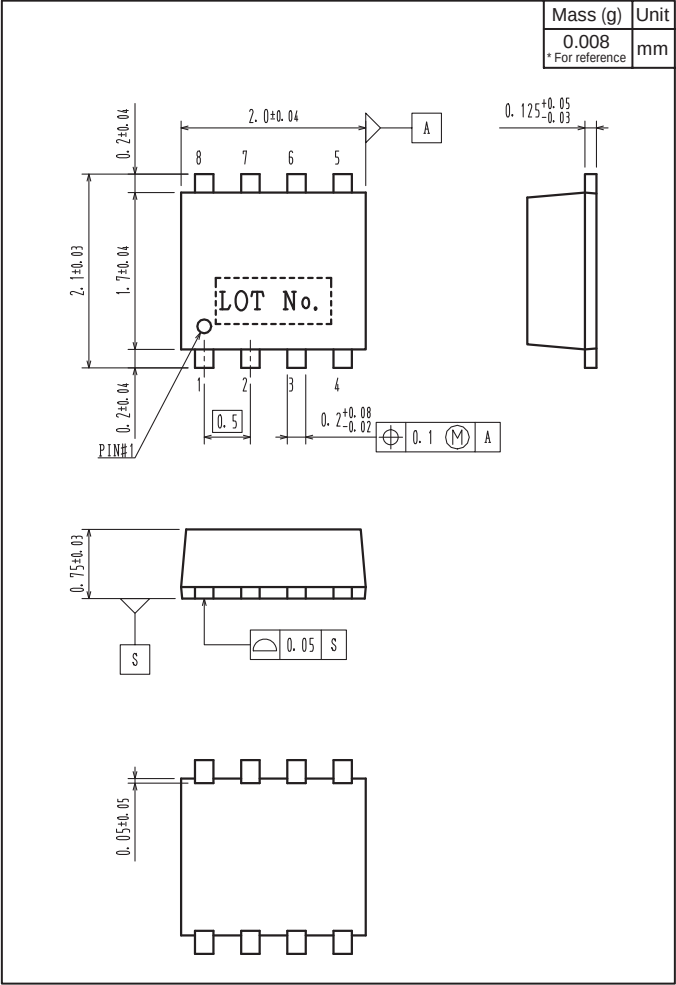
2-1. Carrier tape size (unit:mm)



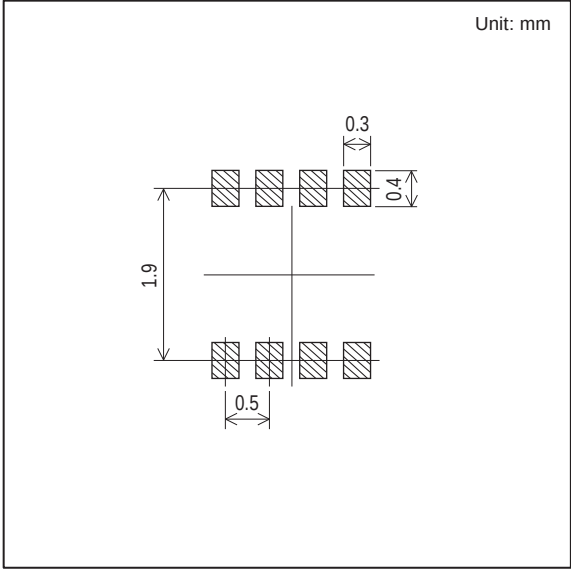
2-2. Device placement direction



Outline Drawing
EMH2604-TL-H



Land Pattern Example



Note on usage : Since the EMH2604 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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